# 13 /Reg for H17/3 PATENT VS

Docket No.: 50090-308

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Akio UENISHI

Serial No.: 09/901,046

Filed: July 10, 2001

For:

SEMICONDUCTOR DEVICE

Group Art Unit: 2811

Examiner: Quang D. Vu

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## **REQUEST FOR RECONSIDERATION**

Commissioner for Patents Washington, DC 20231

Sir:

These remarks are filed in response to the Office Action dated January 14, 2003.

## **REMARKS**

This Request for Reconsideration is responsive to the Office Action dated January 14, 2003. For the following reasons, this application is in condition for allowance and should be passed to issue.

## Rejections Under 35 USC § 102

Claims 2, 3, 5, and 6 are rejected under 35 USC § 102(e) as being anticipated by Usami (6,194,775). This rejection is traversed, and reconsideration and withdrawal thereof respectfully requested. The following is a comparison of the instant invention and the cited prior art.

An aspect of the invention, per claim 2, is a semiconductor device comprising a semiconductor substrate and a first insulating film formed on the semiconductor substrate.

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